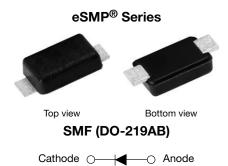
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Vishay General Semiconductor

Surface-Mount TMBS[®] (Trench MOS Barrier Schottky) Rectifier



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS			
I _{F(AV)}	1.0 A		
V _{RRM}	200 V		
I _{FSM}	30 A		
V_F at I_F = 1 A (T_A = 125 °C)	0.64 V		
T _J max.	175 °C		
Package	SMF (DO-219AB)		
Circuit configuration	Single		

FEATURES

- Trench MOS Schottky technology
- · Low profile package
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · Wave and reflow solderable
- AEC-Q101 gualified available - Automotive ordering code: base P/NHM3
- Compatible to SOD-123W package case outline
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, DC/DC converters, and polarity protection in commercial, industrial, and automotive applications.

MECHANICAL DATA

Case: SMF (DO-219AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V1F22	UNIT	
Device marking code		V1D		
Maximum repetitive peak reverse voltage	V _{RRM}	200	V	
Maximum DC reverse voltage	V _{DC}	160	V	
Maximum average forward rectified current (fig.1)	I _{F(AV)} ⁽¹⁾	1.0	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30	А	
Operating junction temperature range	T _J ⁽²⁾	-40 to +175	°C	
Storage temperature range	T _{STG}	-55 to +175		

Notes

⁽¹⁾ Free air, mounted on recommended copper pad area

⁽²⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{eJA}$

RoHS

COMPLIANT

HALOGEN

FREE

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V1F22

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 0.5 A	– T _A = 25 °C		0.73	-	V
	I _F = 1.0 A		V _F (1)	0.80	0.88	
	I _F = 0.5 A	– T _A = 125 °C	VF	0.57	-	
	I _F = 1.0 A			0.64	0.72	
Reverse current	V _B = 160 V	$ \begin{array}{c c} T_{A} = 25 \ ^{\circ}C \\ \hline T_{A} = 125 \ ^{\circ}C \\ \hline T_{A} = 25 \ ^{\circ}C \\ \end{array} \end{array} \qquad \qquad$		0.1	-	
	$v_{\rm R} = 100 v$		L_ (2)	100	-	
	$V_{R} = 200 V$ $T_{A} = 25 °C$ $T_{A} = 125 °C$		-	35	μA	
		T _A = 125 °C		300	1500	
Typical junction capacitance	4.0 V, 1 MHz		CJ	75	-	pF

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \degree c$ unless otherwise noted)				
PARAMETER	SYMBOL	V1F22	UNIT	
Typical thermal resistance	R _{0JA} (1)(2)	125	°C/W	
	R _{0JM} ⁽³⁾	30	0/11	

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

 $^{(2)}$ Free air, mounted on recommended copper pad area; thermal resistance $R_{\theta JA}$ - junction to ambient

 $^{(3)}$ Mounted on recommended copper pad area; thermal resistance $R_{\theta JM}$ - junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V1F22-M3/H	0.015	Н	3000	7" diameter plastic tape and reel	
V1F22-M3/I	0.015	I	10 000	13" diameter plastic tape and reel	
V1F22HM3/H ⁽¹⁾	0.015	Н	3000	7" diameter plastic tape and reel	
V1F22HM3/I ⁽¹⁾	0.015	I	10 000	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

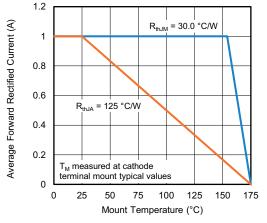


Fig. 1 - Maximum Forward Current Derating Curve

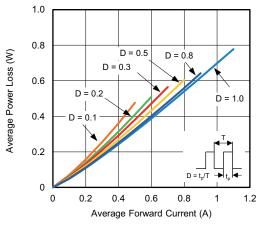


Fig. 2 - Average Power Loss Characteristics

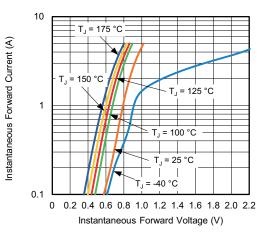


Fig. 3 - Typical Instantaneous Forward Characteristics

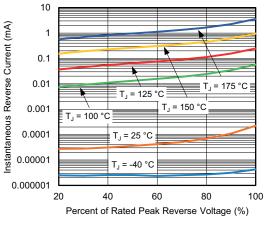


Fig. 4 - Typical Reverse Leakage Characteristics

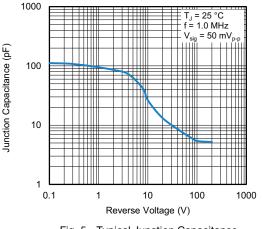


Fig. 5 - Typical Junction Capacitance

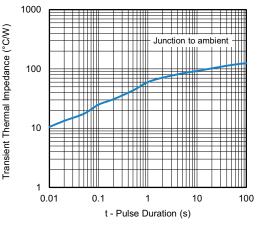


Fig. 6 - Typical Transient Thermal Impedance

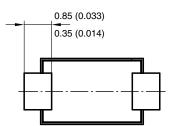
Revision: 13-May-2020

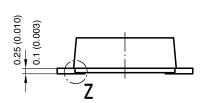
3

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PACKAGE OUTLINE DIMENSIONS in millimeters (inches)

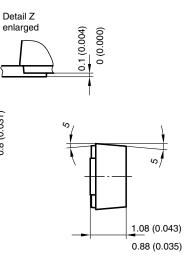




2.9 (0.114)

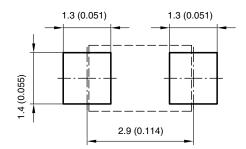
2.7 (0.106)

3.9 (0.154) 3.5 (0.138)



Foot print recommendation:

1.2 (0.047) 0.8 (0.031)



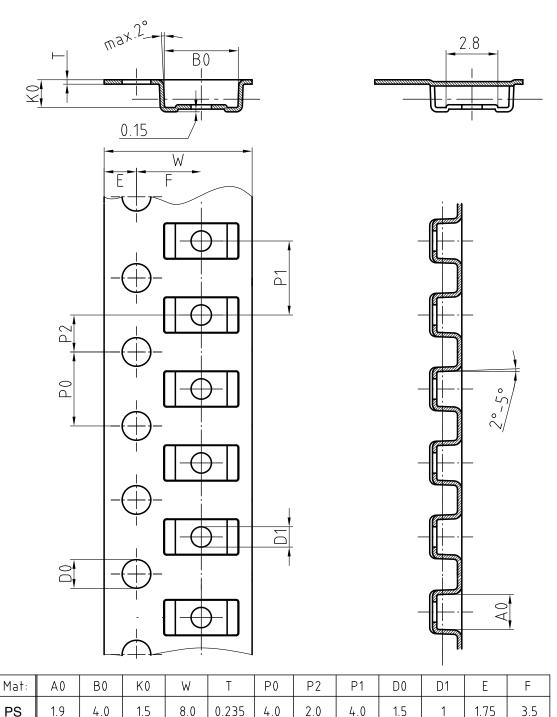
Created - Date: 15. February 2005 Rev. 3 - Date: 13. March 2007 Document no.:S8-V-3915.01-001 (4) 17247

1.9 (0.075) 1.7 (0.067)



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BLISTERTAPE DIMENSIONS in millimeters: SMF (DO-219AB)



Document-No.: S8-V-3717.02-001 (3)

4.0

1.5

8.0

1.9

18513

PS

4.0

1.5

4.0

1

1.75

3.5

Document Number: 87474

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